

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Kulbinder K. Banger et al.  
Title: SINGLE SOURCE PRECURSORS FOR TERNARY  
CHALCOPYRITE MATERIALS, AND METHODS OF MAKING AND  
USING THE SAME  
Serial No.: 10/698,118 Art Unit: not yet assigned  
Filed: October 31, 2003 Examiner: not yet assigned  
Docket: 35089US1

INFORMATION DISCLOSURE STATEMENT

Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

Sir:

In accordance with 37 C.F.R. § 1.98, applicant is submitting herewith Form PTO-1449 listing references for consideration by the Examiner. Also submitted herewith is a legible copy of each reference listed.

If any further fees are required by this communication, please charge such fees to our Deposit Account No. 16-0820, Order No. 35089US1.

Respectfully submitted,  
PEARNE & GORDON LLP

By   
Steven J. Solomon, Reg. No. 48719

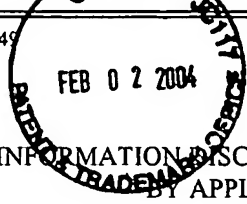
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Date: January 29, 2004

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Signature of Depositor

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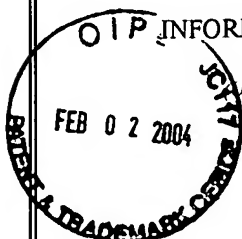
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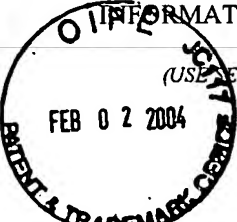
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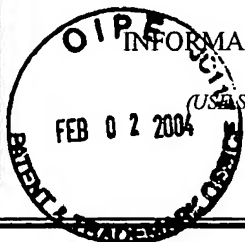
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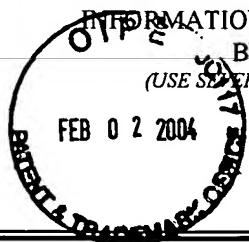
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